

**FEATURES:**

- Pin-out compatible with standard '125 Logic products
- $5\Omega$  A/B bi-directional bus switch
- Isolation under power-off conditions
- Over-voltage tolerant
- Latch-up performance exceeds 100mA
- $V_{CC} = 2.3V - 3.6V$ , Normal Range
- ESD > 2000V per MIL-STD-883, Method 3015;  
> 200V using machine model ( $C = 200pF$ ,  $R = 0$ )
- Available in QSOP and TSSOP packages

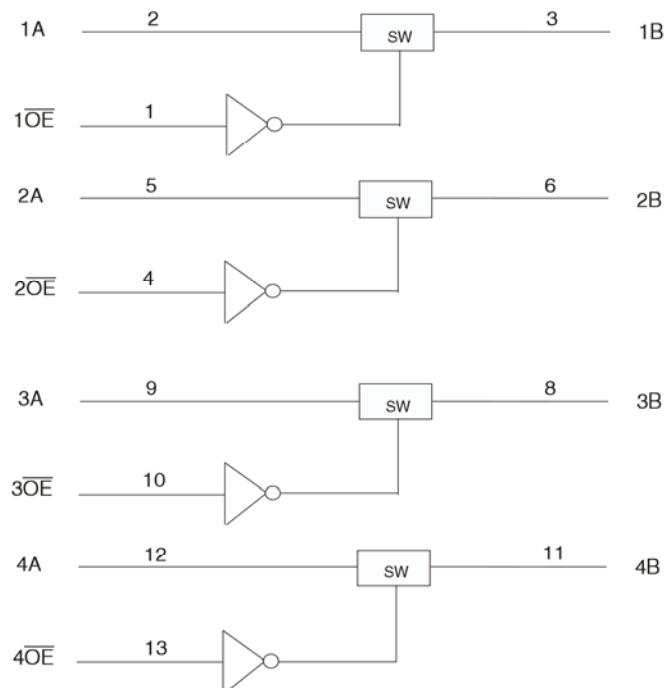
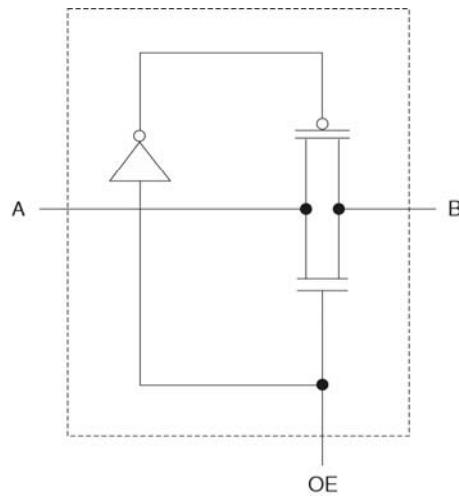
**APPLICATIONS:**

- 3.3V High Speed Bus Switching and Bus Isolation

**DESCRIPTION:**

The CBTLV3125 features four independent switches. Each switch is enabled when the associated output-enable ( $\overline{OE}$ ) input is low.

To ensure the high-impedance state during power up or power down,  $\overline{OE}$  should be tied to  $V_{CC}$  through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

**FUNCTIONAL BLOCK DIAGRAM****SIMPLIFIED SCHEMATIC, EACH SWITCH****NOTE:**

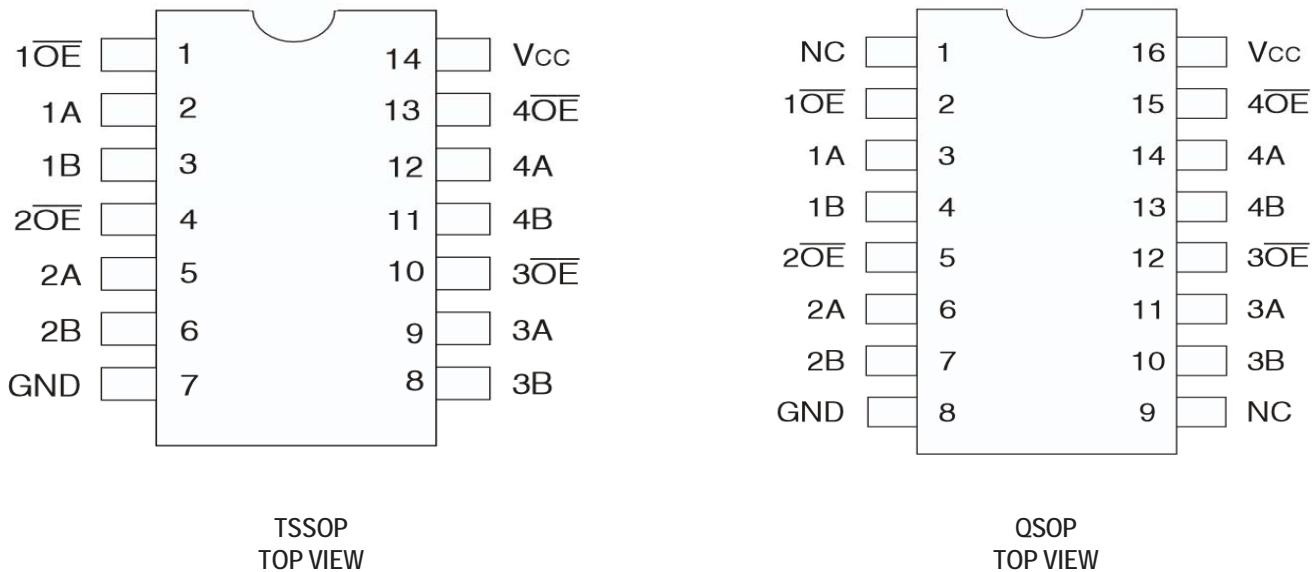
1. Pin numbers shown apply to the 14-pin TSSOP package.

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**INDUSTRIAL TEMPERATURE RANGE**

DECEMBER 2014

## PIN CONFIGURATION



## ABSOLUTE MAXIMUM RATINGS<sup>(1)</sup>

Symbol	Description	Max	Unit
Vcc	Supply Voltage Range	-0.5 to +4.6	V
VI	Input Voltage Range	-0.5 to +4.6	V
	Continuous Channel Current	128	mA
IIK	Input Clamp Current, $V_{I/O} < 0$	-50	mA
TSTG	Storage Temperature	-65 to +150	°C

### NOTE:

1. Stresses greater than those listed under ABSOLUTE MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

## FUNCTION TABLE<sup>(1)</sup>

Input $\overline{OE}$	Inputs/Outputs
L	A Port = B Port
H	Disconnect

### NOTE:

1. H = HIGH Voltage Level  
L = LOW Voltage Level

## OPERATING CHARACTERISTICS, $T_A = 25^\circ C$ <sup>(1)</sup>

Symbol	Parameter	Test Conditions	Min.	Max.	Unit
Vcc	Supply Voltage		2.3	3.6	V
VIH	High-Level Control Input Voltage	Vcc = 2.3V to 2.7V	1.7	—	V
		Vcc = 2.7V to 3.6V	2	—	
VIL	Low-Level Control Input Voltage	Vcc = 2.3V to 2.7V	—	0.7	V
		Vcc = 2.7V to 3.6V	—	0.8	
TA	Operating Free-Air Temperature		-40	85	°C

### NOTE:

1. All unused control inputs of the device must be held at Vcc or GND to ensure proper device operation.

## DC ELECTRICAL CHARACTERISTICS OVER OPERATING RANGE

Following Conditions Apply Unless Otherwise Specified:

Operating Conditions: TA = -40°C to +85°C

Symbol	Parameter	Test Conditions		Min.	Typ. <sup>(1)</sup>	Max.	Unit
V <sub>IK</sub>	Control Inputs, Data Inputs	V <sub>CC</sub> = 3V, I <sub>I</sub> = -18mA		—	—	-1.2	V
I <sub>I</sub>	Control Inputs	V <sub>CC</sub> = 3.6V, V <sub>I</sub> = V <sub>CC</sub> or GND		—	—	±1	µA
I <sub>OZ</sub>	Data I/O	V <sub>CC</sub> = 3.6V, V <sub>O</sub> = 0 or 3.6V, switch disabled		—	—	5	µA
I <sub>OFF</sub>		V <sub>CC</sub> = 0, V <sub>I</sub> or V <sub>O</sub> = 0 to 3.6V		—	—	50	µA
I <sub>CC</sub>		V <sub>CC</sub> = 3.6V, I <sub>O</sub> = 0, V <sub>I</sub> = V <sub>CC</sub> or GND		—	—	10	µA
ΔI <sub>CC</sub> <sup>(2)</sup>	Control Inputs	V <sub>CC</sub> = 3.6V, one input at 3V, other inputs at V <sub>CC</sub> or GND		—	—	300	µA
C <sub>I</sub>	Control Inputs	V <sub>I</sub> = 3V or 0		—	4	—	pF
C <sub>IO(OFF)</sub>		V <sub>O</sub> = 3V or 0, $\overline{OE}$ = V <sub>CC</sub>		—	6	—	pF
R <sub>ON</sub> <sup>(3)</sup>	V <sub>CC</sub> = 2.3V Typ. at V <sub>CC</sub> = 2.5V	V <sub>I</sub> = 0	I <sub>O</sub> = 64mA	—	5	8	Ω
			I <sub>O</sub> = 24mA	—	5	8	
		V <sub>I</sub> = 1.7V	I <sub>O</sub> = 15mA	—	27	40	
	V <sub>CC</sub> = 3V	V <sub>I</sub> = 0	I <sub>O</sub> = 64mA	—	5	7	
			I <sub>O</sub> = 24mA	—	5	7	
		V <sub>I</sub> = 2.4V	I <sub>O</sub> = 15mA	—	10	15	

### NOTES:

1. Typical values are at V<sub>CC</sub> = 3.3V, +25°C ambient.
2. The increase in supply current is attributable to each current that is at the specified voltage level rather than V<sub>CC</sub> or GND.
3. This is measured by the voltage drop between the A and B terminals at the indicated current through the switch.

## SWITCHING CHARACTERISTICS

Symbol	Parameter	V <sub>CC</sub> = 2.5V ± 0.2V		V <sub>CC</sub> = 3.3V ± 0.3V		Unit
		Min.	Max.	Min.	Max.	
t <sub>PD</sub> <sup>(1)</sup>	Propagation Delay A to B or B to A	—	0.15	—	0.25	ns
t <sub>EN</sub>	Output Enable Time $\overline{OE}$ to A or B	1	4.6	1	4.4	ns
t <sub>DIS</sub>	Output Disable Time $\overline{OE}$ to A or B	1	3.9	1	4.2	ns

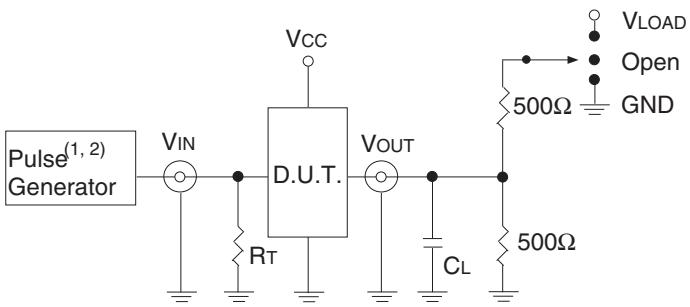
### NOTE:

1. The propagation delay is the calculated RC time constant of the typical on-state resistance of the switch and the specified load capacitance driven by an ideal voltage source (zero output impedance).

## TEST CIRCUITS AND WAVEFORMS

### TEST CONDITIONS

Symbol	$V_{CC}^{(1)} = 3.3V \pm 0.3V$	$V_{CC}^{(2)} = 2.5V \pm 0.2V$	Unit
$V_{LOAD}$	6	$2 \times V_{CC}$	V
$V_{IH}$	3	$V_{CC}$	V
$V_T$	1.5	$V_{CC}/2$	V
$V_{LZ}$	300	150	mV
$V_{HZ}$	300	150	mV
$C_L$	50	30	pF



Test Circuits for All Outputs

#### DEFINITIONS:

$CL$  = Load capacitance: includes jig and probe capacitance.

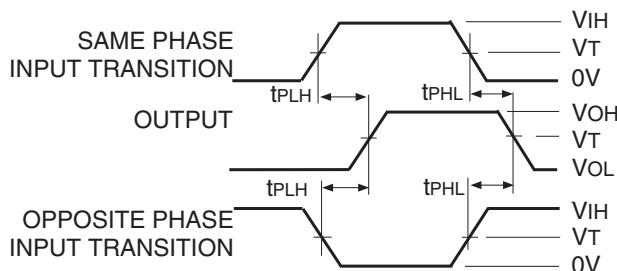
$R_T$  = Termination resistance: should be equal to  $Z_{OUT}$  of the Pulse Generator.

#### NOTES:

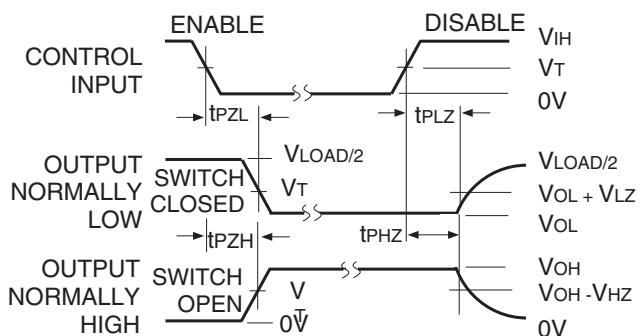
- Pulse Generator for All Pulses: Rate  $\leq 10MHz$ ;  $t_f \leq 2.5ns$ ;  $t_r \leq 2.5ns$ .
- Pulse Generator for All Pulses: Rate  $\leq 10MHz$ ;  $t_f \leq 2ns$ ;  $t_r \leq 2.5ns$ .

### SWITCH POSITION

Test	Switch
$t_{PLZ}/t_{PZL}$	$V_{LOAD}$
$t_{PHZ}/t_{PZH}$	GND
$t_D$	Open



Propagation Delay



Enable and Disable Times

## ORDERING INFORMATION

